

HAT2280R

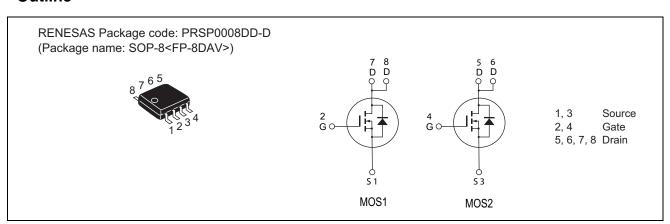
Silicon N Channel Power MOSFET Power Switching

R07DS1372EJ0201 Rev.2.01 Jan 20, 2017

Features

- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)} = 27 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	6.6	A
Drain peak current	I _{D(pulse)} Note1	52.8	А
Body-drain diode reverse drain current	I _{DR}	6.6	A
Avalanche current	I _{AP} Note 2	6.6	A
Avalanche energy	E _{AR} Note 2	4.3	mJ
Channel dissipation	Pch Note3	1.5	W
Channel dissipation	Pch Note4	2.3	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. 1 Drive operation : When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s
- 4. 2 Drive operation: When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s

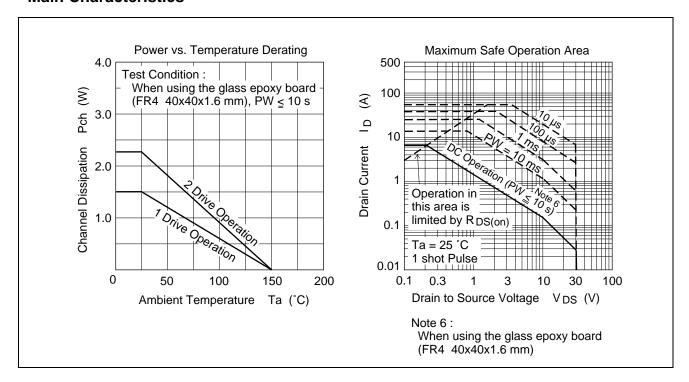
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

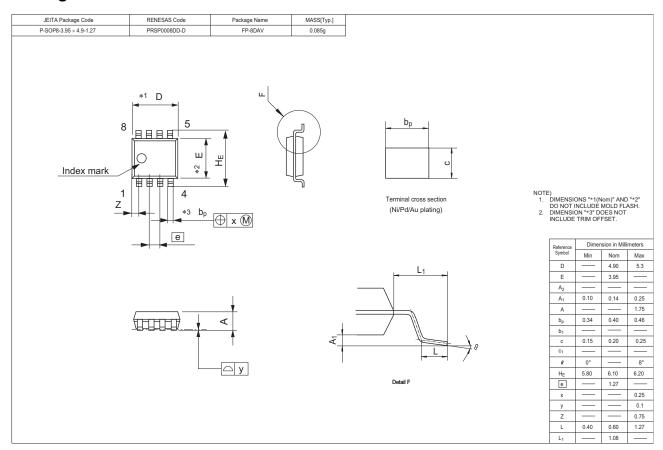
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltege drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.0	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	27	34	mΩ	$I_D = 3.3 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$
resistance	R _{DS(on)}	_	40	57	mΩ	$I_D = 3.3 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note5}}$
Forward transfer admittance	y _{fs}	5	8.5	_	S	$I_D = 3.3 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note5}}$
Input capacitance	Ciss	_	410	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	110	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	41	_	pF	f = 1 MHz
Total gate charge	Qg	_	3.0	_	nc	V _{DD} = 10 V
Gate to source charge	Qgs	_	1.1	_	nc	V _{GS} = 4.5 V
Gate to drain charge	Qgd	_	1.1	_	nc	I _D = 6.6 A
Turn-on delay time	t _{d(on)}	_	5	_	ns	$V_{GS} = 10 \text{ V}, I_D = 3.3 \text{ A}$
Rise time	tr	_	13.5	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t _{d(off)}	_	34	_	ns	$R_L = 0.3 \Omega$
Fall time	t _f	_	3.4	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	0.85	1.11	V	IF = 6.6 A, V _{GS} = 0 Note5
Body-drain diode reverse recovery	t _{rr}	_	16	_	ns	IF = 6.6 A, V _{GS} = 0
time						diF/ dt = 100 A/ μs

Notes: 5. Pulse test

Main Characteristics



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HAT2280R-EL-E	2500 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales Office to check the state of production before ordering the product.

General Precautions in the Handling of Power MOSFET and IGBT Products

The following usage notes are applicable to general purpose Power MOSFET and IGBT products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Derating

Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect a reliability even if it are within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook (Recommendation for Handling and Usage of Semiconductor Devices) and individual reliability data.

2. Quality grade

- The quality grade of this product is "Standard".
- If you plan to use this product to "High quality" application, please inform to Renesas.
- Fail safe system is necessary to prevent malfunction even if this product is broken.

Notice

- Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics
- assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.

 Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or
- You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.

 Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated belo w.
- "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc.
- High Quality*: Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc.

- "High Quality": Transportation equipment (automobiles, trains, ships, etc.); tra ffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc.

 Reneasa Electronics products are neither intended nor authorized for use in products or systems may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application for which it is not intended. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for which the reproduct is not intended by Renesas Electronics.

 You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics products beyond such specified ranges.

 Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction revention, appropriate treatment for axing degradation or which are a product a please contact a Renessa Electronics sales of file for details as to environmental and material environmental compatibility of each Renessa Electronics product. Please use Renessa Electronics and material environmental environmental compatibility of each Renessa Electronics product.
- Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
 Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the militar y, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations.
 It is the responsibility of the buyer or distributor of Renesas Electronics products, who distributes, disposes of, or otherwise places the product with a third part y, to notify such third party in advance of the contents and conditions set forth in this document, Renesas Electronics assumes no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products
- products.

 This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 12. Please contact a Renessas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.

 (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.

 (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

以下"注意事项"为从英语原稿翻译的中文译文,仅作为参考译文,英文版的"Notice"具有正式效力。

注意事项

- 本文档中所记载的关于电路、软件和其他相关信息仅用于说明半导体产品的操作和应用实例。用户如在设备设计中应用本文档中的电路、软件和相关信息,请自行负责。对于用户或第三方因使用上述电路、软件或信息而遭受的任何损失,瑞萨电子不承担任何责任。
 在注意本文档外记载的信息的过程中,瑞萨电子已尽量做到合理注意,但是,瑞萨电子并不保证这些信息都是准确无误的。用户因本文档中所记载的信息的错误或遗漏而遭受的任何损失,瑞萨电子不承担任何责任。

对于因使用本文档中的谐游中电子产品或技术信息而造成的侵权行为或因此而侵犯第三方的专利、版权或其他知识产权的行为,海严电子小界在时间成在。并入1870年2017年12月,1870年18月

RENESAS

SALES OFFICES

Renesas Electronics Corporation

http://www.renesas.com

Refer to "http://www.renesas.com/" for the latest and detailed information.

Renesas Electronics America Inc. 2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3 Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Boume End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tei: +86-21-2226-0888, Fax: +88-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

ros. rodovz-or.ro-sout, rax: +odd z-8175-9570

Renesas Electronics Singapore Pte. Ltd.
80 Bendemer Road, Unit #06-02 Hyffux Innovation Centre, Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050
Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tet. +60-3-7955-9390, Fax. +60-3-7955-9510

Renesas Electronics India Pvt. Ltd. No.777C, 100 Feet Road, HAL Stage, Indiranagar, Bangalore, India Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd. 12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141